



150V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
150V	67mΩ @ V _{GS} = 10V	4.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- High frequency switching
- Synchronous rectifications
- DC-DC converters

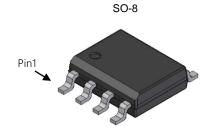
Features and Benefits

- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

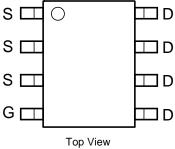
https://www.diodes.com/quality/product-definitions/

Mechanical Data

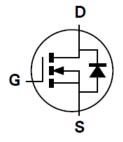
- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202. Method 208 (63)
- Weight: 0.074 grams (Approximate)



Top View



Pin-Out



Equivalent Circuit

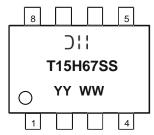
Ordering Information (Note 4)

Part Number	Pookage	Pac	king
Part Number	Раскаде	Qty.	Carrier
DMT15H067SSS-13	SO-8	2,500	Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



);; = Manufacturer's Marking T15H67SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	150	V
Gate-Source Voltage		Vgss	±20	V
Continuous Prain Correct (Note C) // 40)/	T _A = +25°C T _A = +70°C	l _D	4.5 3.6	А
Continuous Drain Current (Note 6) Vgs = 10V	$T_C = +25$ °C $T_C = +70$ °C	lo	13 10	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	28	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	13	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle:	Ism	28	Α	
Avalanche Current, L = 1mH		IAS	11.7	A
Avalanche Energy, L = 1mH		Eas	68.4	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	1.3	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	94	°C/W
Total Power Dissipation (Note 6)	P _D	2	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	59	°C/W
Thermal Resistance, Junction to Case (Note 6)	R ₀ JC	7	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

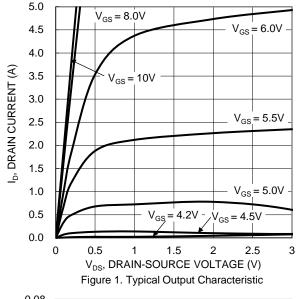
Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

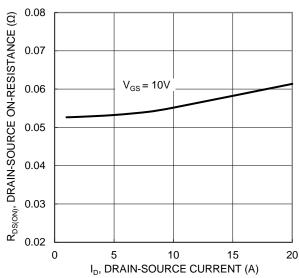
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	150	_	_	V	$V_{GS} = 0V, I_D = 10mA$
Zero Gate Voltage Drain Current	IDSS		_	1	μA	V _{DS} = 120V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS(ON)		53	67	mΩ	Vgs = 10V, ID = 4.1A
Diode Forward Voltage	VsD	_	8.0	1	V	V _G S = 0V, I _S = 4.1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		425			V _{DS} = 75V, V _{GS} = 0V f = 1MHz
Output Capacitance	Coss	_	82	_	pF	
Reverse Transfer Capacitance	Crss	_	2.8	_		
Gate Resistance	Rg		1.4	1	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$ f = 1MHz
Total Gate Charge	Qg	_	6.4	_		V _{DS} = 75V, I _D = 4.1A, V _{GS} = 10V
Gate-Source Charge	Qgs	_	3	_	nC	
Gate-Drain Charge	Q _{gd}	_	1.6	_		
Turn-On Delay Time	td(ON)	_	6.4	_		$V_{DS} = 75V, V_{GS} = 10V,$ $I_{D} = 4.1A, R_{g} = 6\Omega$
Turn-On Rise Time	t _R	_	2.9	_		
Turn-Off Delay Time	tD(OFF)	_	8.4	_	ns	
Turn-Off Fall Time	t _F	_	5.4	_		
Reverse Recovery Time	trr		47	_	ns	I 4 1 0 di/dt 100 0 / · · -
Reverse Recovery Charge	Qrr	_	91	_	$\frac{100}{\text{nC}}$ IF = 4.1A, di/dt = 100A/ μ	

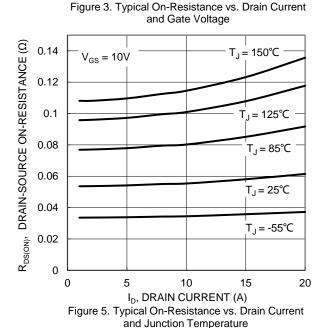
Notes:

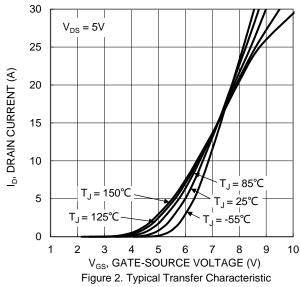
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.

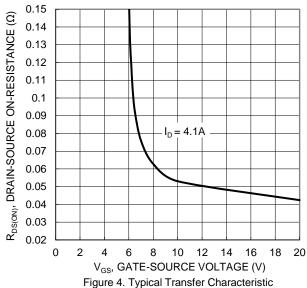


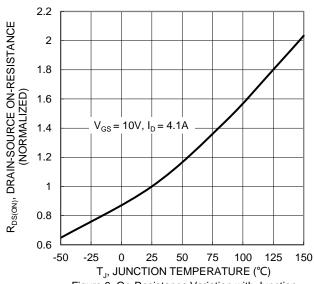






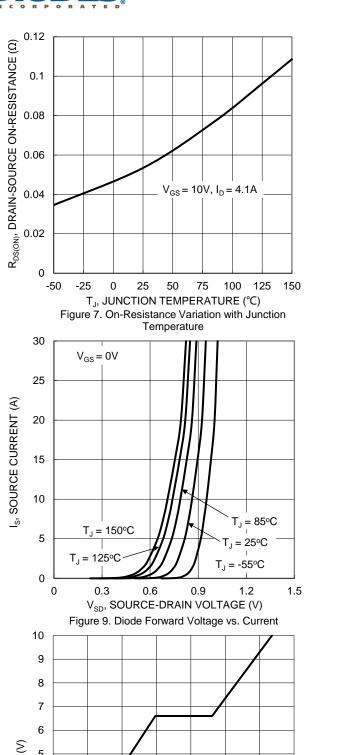


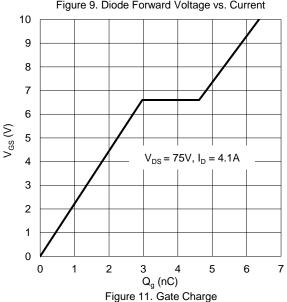


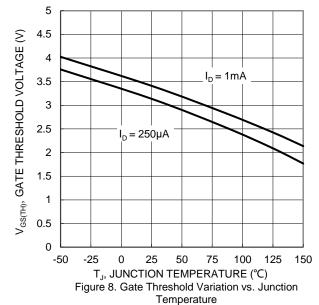


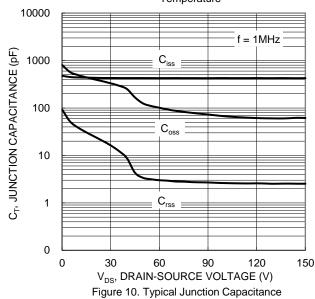


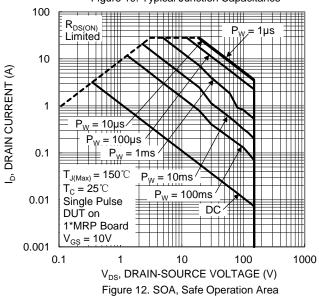














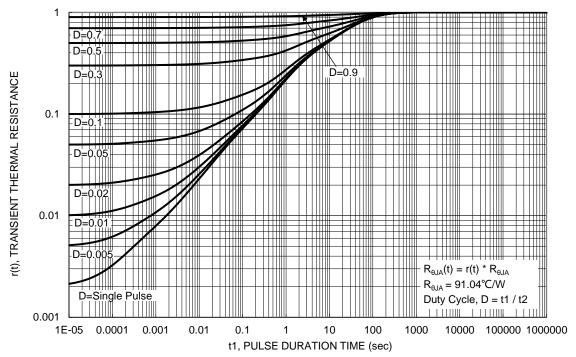


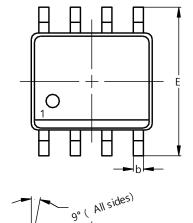
Figure 13. Transient Thermal Resistance

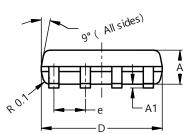


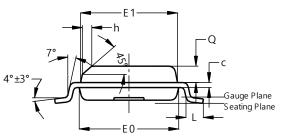
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





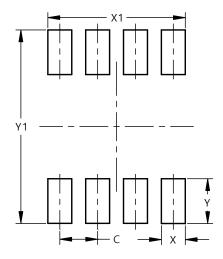


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A 1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h			0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Υ	1.505
Y1	6.50



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